- 7. (a) Explain the working principle of a Schottky diode. Mention its applications and advantages.
 - (b) What happens if the transistor is not biased properly? Explain the C-V characteristics of a transistor.

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Total Pages: 04

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May 2024

B. Tech. (IT/CSE-AIML) (Sixth Semester) Electronic Devices (OEC-CS-601-IV)

Time: 3 Hours]

[Maximum Marks: 75

Note: It is compulsory to answer all the questions
(1.5 marks each) of Part A in short. Answer
any four questions from Part B in detail.

Different sub-parts of a question are to be attempted adjacent to each other.

Part A

- 1. (a) How does the energy gap in a semiconductor vary, when doped with a trivalent impurity?
 - 1.5
 - (b) Why is collector region wider than emitter region in BJT?
 - (c) Explain the switching characteristic of PN junction diode. 1.5
 - (d) What is the condition for thermal stability and thermal resistance?

90

- Define cut-off, active and saturation regions in a transistor. 1.5 (f) Why do the output characteristics of a CB transistor have a slight upward slope? 1.5 In a BJT, the emitter current is 12 mA and the emitter current is 1.02 times the collector
- current. Find the base current.
- Why the input impedance of FET is more (h) than that of a BJT?
- Differentiate between LED and Solar cell. 1.5
- Discuss the twin-tub CMOS process in detail. (j) 1.5

Part B

- Derive an expression for total diode current starting from Boltzmann relationship in terms of the applied voltage.
 - Detail the construction of an n-channel MOSFET of depletion type. Draw and explain its characteristics.
- Discuss in detail the fabrication steps of a pMOS transistor.

- Designate the charge carrier generation and separation mechanism in solar cells with respect to the solar light illumination.
- (a) Sketch the static characteristics of a common base transistor and bring out the essential features of input and output characteristics.

- Compare the following:
 - Ion implantation and Diffusion
 - Dielectric and Poly-silicon film deposition.
- Illustrate the applications of PIN diode and (a) photo detectors toward society in terms of medical, research and development and information technology.
 - Draw the hybrid-π equivalent of a CE transistor for high frequency and explain the significance of each parameter.
- **6.** (a) What is photolithography? Explain the photolithography process in detail.
 - Explain the formation of energy bands in solids. On the basis of energy bands distinguish between a metal, a semiconductor and an insulator.